

Features

- 650-Volt Schottky Rectifier
- Ceramic Package Provides 2.5kV Isolation
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Positive Temperature Coefficient on V_F

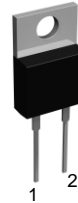
Benefits

- Electrically Isolated Package
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- HVAC
- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter Stages
- AC/DC converters

Package



TO-220 Isolated



Maximum Ratings ($T_c = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	650	V		
V_{RSM}	Surge Peak Reverse Voltage	650	V		
V_{DC}	DC Blocking Voltage	650	V		
I_F	Continuous Forward Current	38 19 10	A	$T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=158^\circ\text{C}$	Fig. 3
I_{FRM}	Repetitive Peak Forward Surge Current	59 42.5	A	$T_c=25^\circ\text{C}$, $t_p=10$ ms, Half Sine Pulse $T_c=110^\circ\text{C}$, $t_p=10$ ms, Half Sine Pulse	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	90 70	A	$T_c=25^\circ\text{C}$, $t_p=10$ ms, Half Sine Pulse $T_c=110^\circ\text{C}$, $t_p=10$ ms, Half Sine Pulse	Fig. 8
I_{FMax}	Non-Repetitive Peak Forward Surge Current	890 700	A	$T_c=25^\circ\text{C}$, $t_p=10$ ms, Pulse $T_c=110^\circ\text{C}$, $t_p=10$ ms, Pulse	Fig. 8
P_{tot}	Power Dissipation	150 60	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	$V_R=0-650\text{V}$	
$\int i^2 dt$	i^2t value	40.5 24.5	A^2s	$T_c=25^\circ\text{C}$, $t_p=10$ ms $T_c=110^\circ\text{C}$, $t_p=10$ ms	
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.27 1.38	1.5 1.6	V	$I_F = 10\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 10\text{ A}$ $T_J = 175^\circ\text{C}$	Fig. 1
I_R	Reverse Current	10 25	50 200	μA	$V_R = 650\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}$ $T_J = 175^\circ\text{C}$	Fig. 2
Q_C	Total Capacitive Charge	25		nC	$V_R = 400\text{ V}$, $I_F = 10\text{ A}$ $di/dt = 500\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	Fig. 5
C	Total Capacitance	640 66 48		pF	$V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$	Fig. 6
E_C	Capacitance Stored Energy	3.6		μJ	$V_R = 400\text{ V}$	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	2.5	$^\circ\text{C}/\text{W}$	Fig. 9

Typical Performance

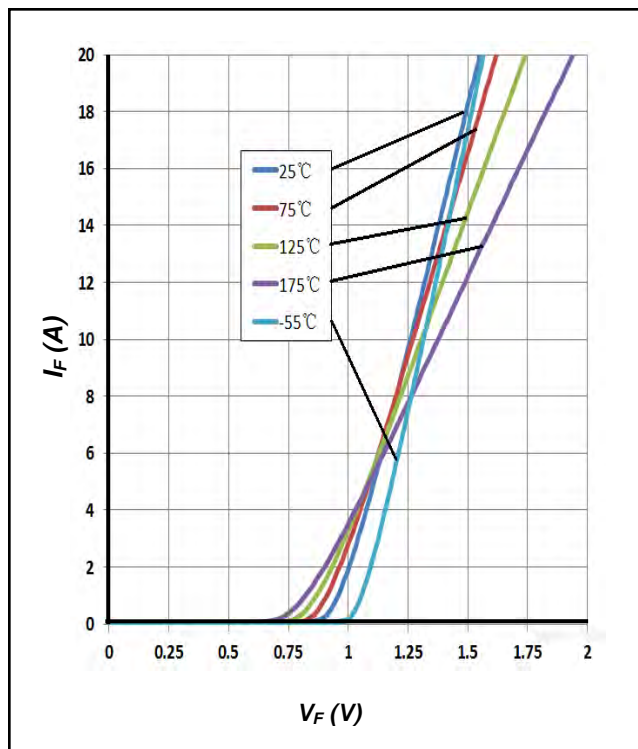


Figure 1. Forward Characteristics

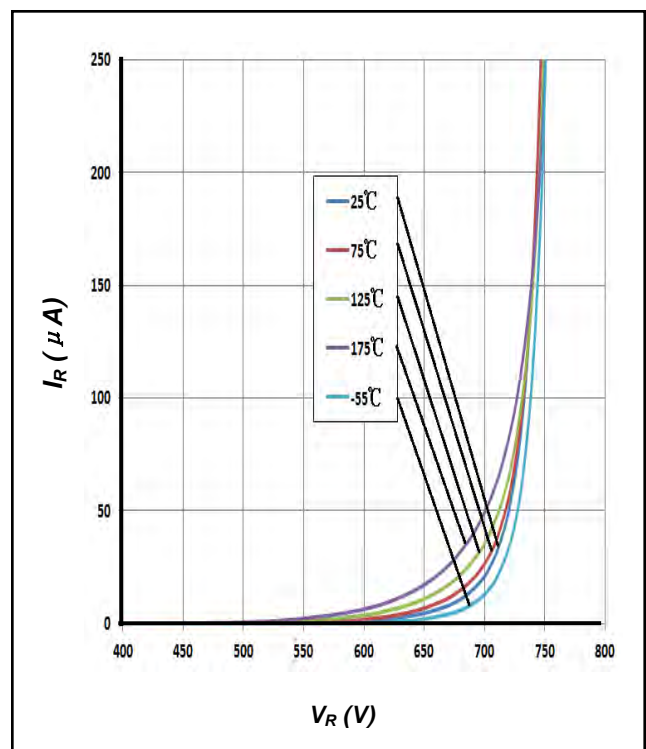


Figure 2. Reverse Characteristics

Typical Performance

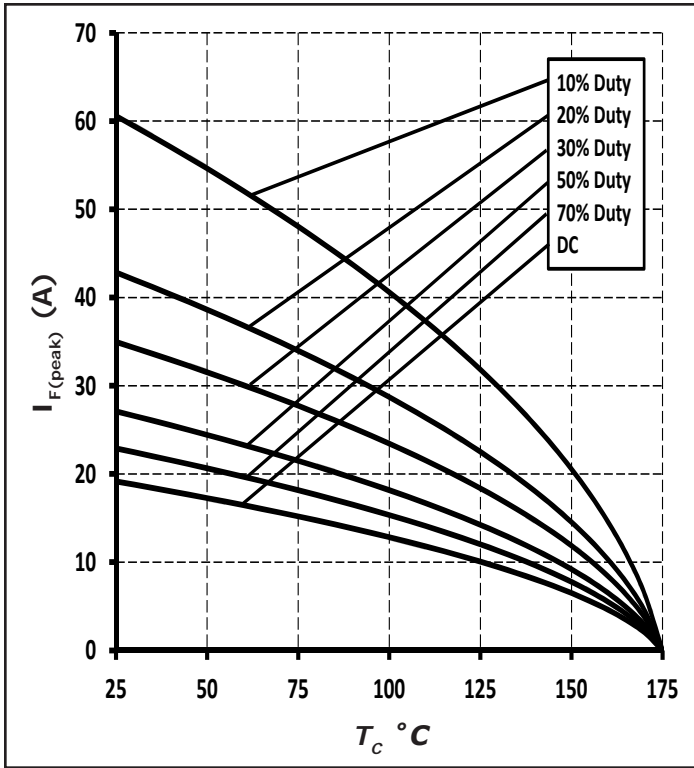


Figure 3. Current Derating

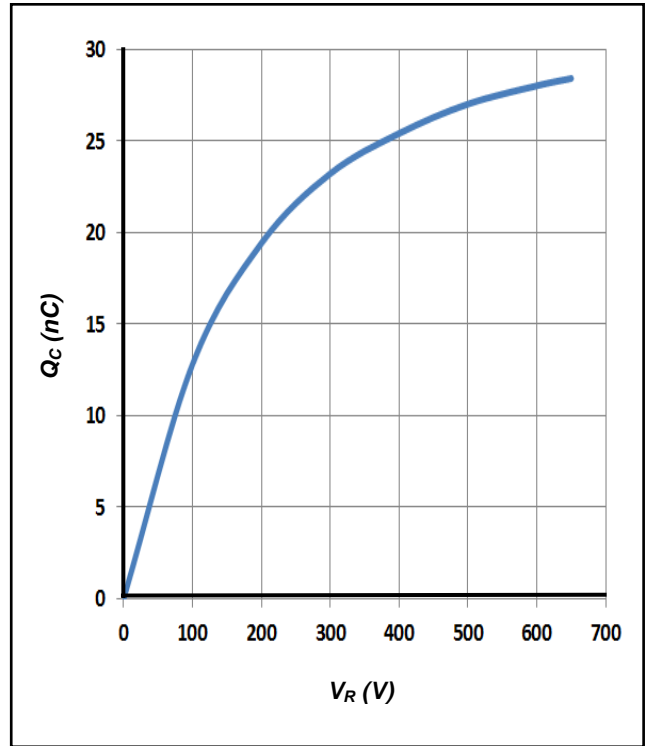


Figure 4. Power Derating

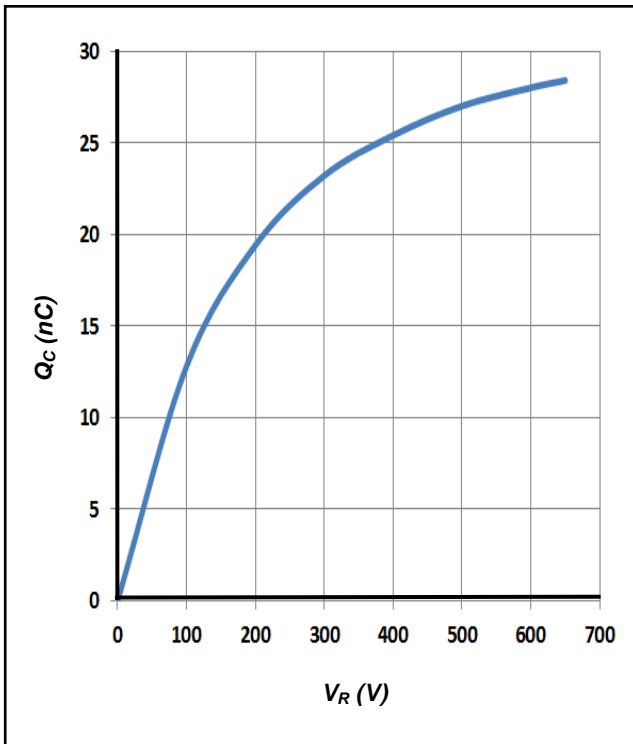


Figure 5. Total Capacitance Charge vs. Reverse Voltage

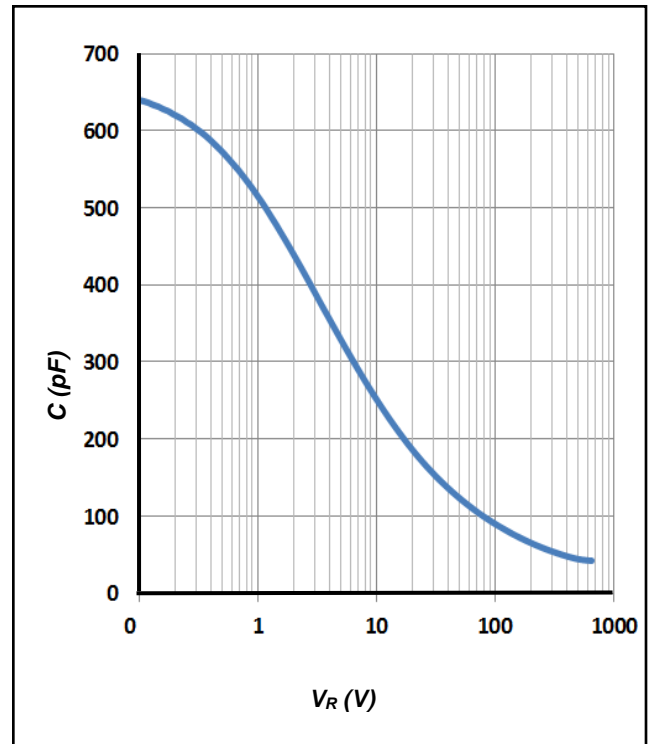


Figure 6. Capacitance vs. Reverse Voltage

Typical Performance

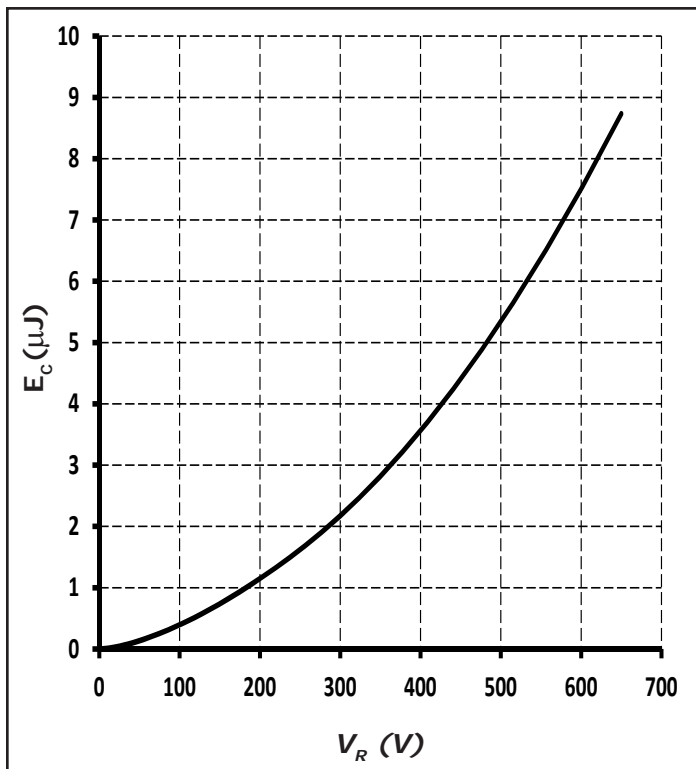


Figure 7. Capacitance Stored Energy

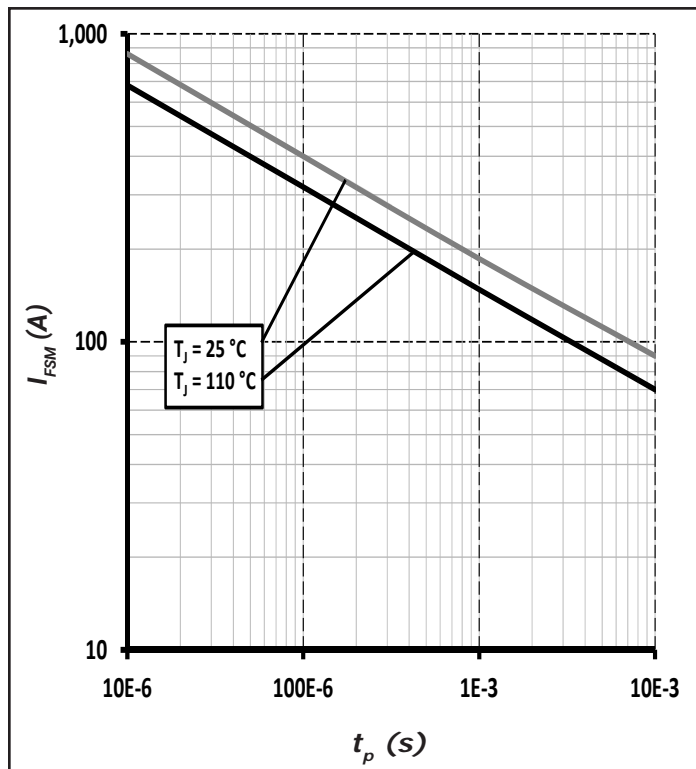


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

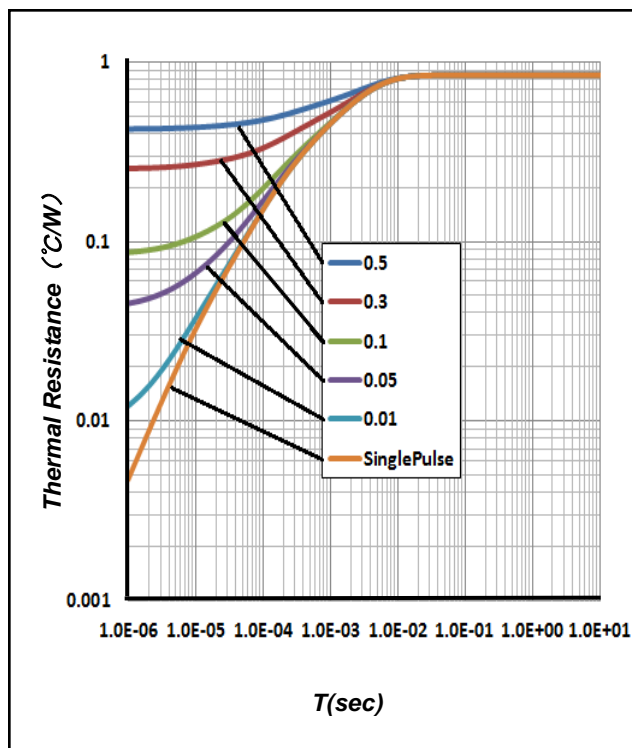
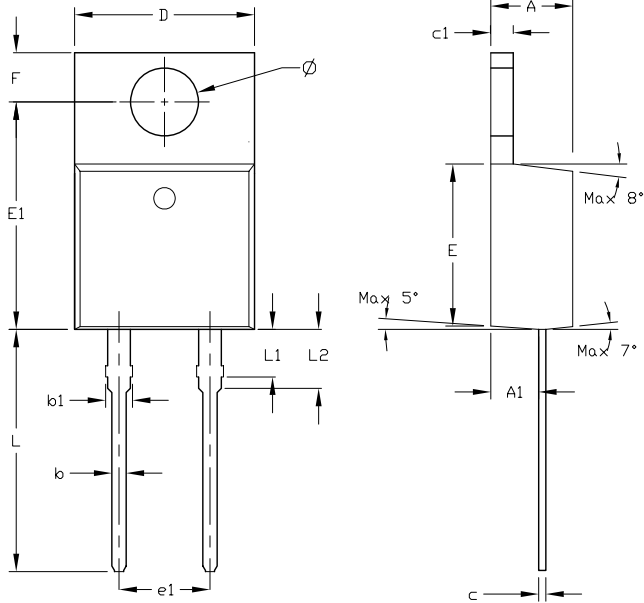


Figure 9. Transient Thermal Impedance

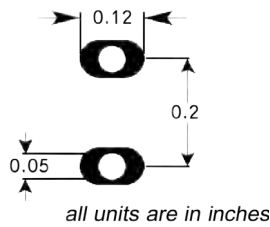
Package Dimensions

Package TO-220-2



Symbol	Dimension in Millimeters		Dimension in Inches	
	Min	Max	Min	Max
A	4.420	4.720	0.174	0.186
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.360	0.460	0.014	0.018
c1	1.170	1.370	0.046	0.054
D	9.960	10.250	0.392	0.404
E	8.990	9.290	0.354	0.366
E1	12.550	12.850	0.494	0.506
e1	4.980	5.180	0.196	0.204
F	2.590	2.890	0.102	0.114
L	13.080	13.480	0.515	0.531
L1	2.470	2.870	0.097	0.113
L2	3.200	3.600	0.126	0.142
\varnothing	3.790	3.890	0.149	0.153
$\theta 1$	Max 8°			
$\theta 2$	Max 7°			
$\theta 3$	Max 5°			
T	Max 0.0205		Max 0.52	

Recommended Solder Pad Layout



TO-220-2